

Features

- Split Gate Trench MOSFET Technology
- · Excellent Package for Heat Dissipation
- High Density Cell Design for Low R_{DS(ON)}
- · Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- · Moisture Sensitivity Level 1

Maximum Ratings

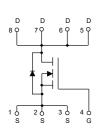
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 20°C/W Junction to Ambient(t≤10S)⁽²⁾
- Thermal Resistance: 50°C/W Junction to Ambient(Steady-State)⁽²⁾
- Thermal Resistance: 1.04°C/W Junction to Case(Steady-State)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	120	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	88	Α
Pulsed Drain Current ⁽³⁾	I _{DM}	352	Α
Total Power Dissipation	P _D	120	W
Single Pulsed Avalanche Energy ⁽⁴⁾	E _{AS}	400	mJ

Note:

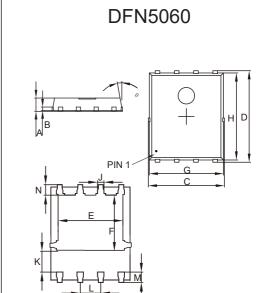
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The Power dissipation P_{DSM} is based on $R_{\theta JA}$ t≤ 10s and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. $T_J=25$ °C, $V_{DD}=50V$, $R_G=25\Omega$, L=2mH.

Internal Structure and Marking Code





N-CHANNEL MOSFET



DIMENSIONS					
DIM INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.031	0.047	0.80	1.20	
В	0.010		.010 0.254		TYP.
С	0.193	0.222	4.90	5.64	
D	0.232	0.250	5.90	6.35	
Е	0.148	0.167	3.75	4.25	
F	0.126	0.154	3.20	3.92	
G	0.189	0.213	4.80	5.40	
Н	0.222	0.239	5.65	6.06	
K	0.045	0.059	1.15	1.50	
J	0.012	0.020	0.30	0.50	
L	0.046	0.054	1.17	1.37	
М	0.012	0.028	0.30	0.71	
N	0.016	0.028	0.40	0.71	

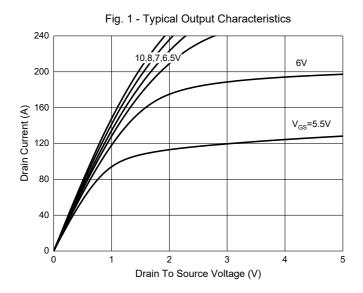


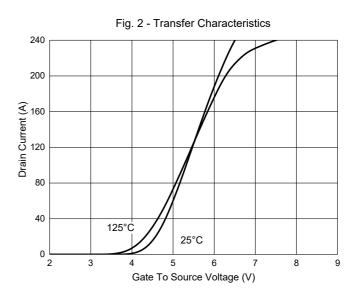
Electrical Characteristics @ 25°C (Unless Otherwise Specified)

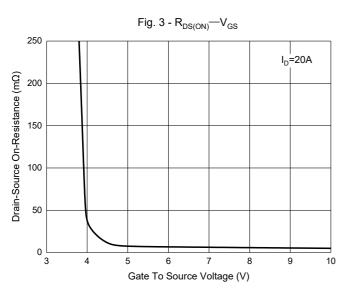
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	120			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3.2	4	V	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		6.2	7.2	mΩ	
Gate Resistance	R_G	f=1MHz, Open drain		0.9		Ω	
Diode Characteristics	-						
Continuous Body Diode Current	Is				88	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.3	V	
Reverse Recovery Time	t _{rr}	L 004 H / H 4004/		84		ns	
Reverse Recovery Charge	Q _{rr}	I _F =20A, dI _F /dt=100A/μs		191		nC	
Dynamic Characteristics	•				•		
Input Capacitance	C _{iss}			4514			
Output Capacitance	C _{oss}	V_{DS} =50V, V_{GS} =0V,f=1MHz		1111		pF	
Reverse Transfer Capacitance	C _{rss}			34			
Total Gate Charge	Q_g			65			
Gate-Source Charge	Q _{gs}	V _{DS} =50V,V _{GS} =10V,I _D =20A		25.9		nC	
Gate-Drain Charge	Q_{gd}			8.9			
Turn-On Delay Time	t _{d(on)}			21.6			
Turn-On Rise Time	t _r	V _{DS} =50V, V _{GEN} =10V,		39.9		no	
Turn-Off Delay Time	t _{d(off)}	$R_G=2.2\Omega$, $I_{DS}=20A$		35		ns	
Turn-Off Fall Time	t _f			40.9			

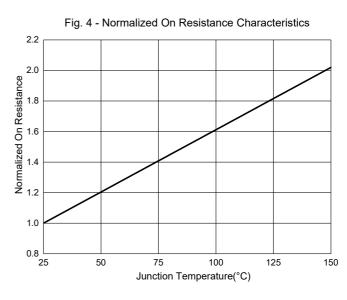


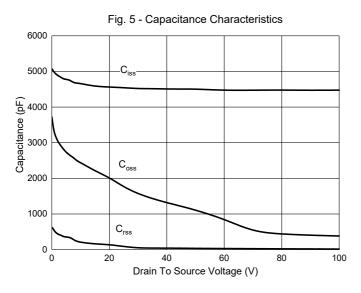
Curve Characteristics

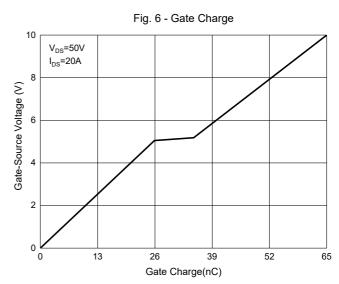






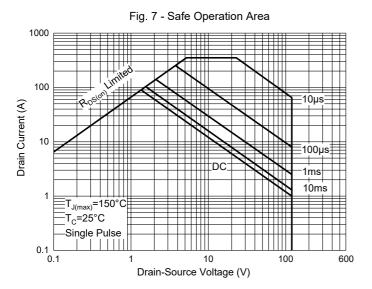








Curve Characteristics





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 5Kpcs/Reel	

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